

VHF variable capacitance diode

FEATURES

- High linearity
- Excellent matching to 2% DMA
- Ultra small plastic SMD package
- C25: 2.8 pF; ratio: 17
- Low series resistance.

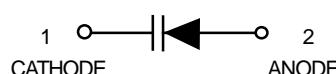
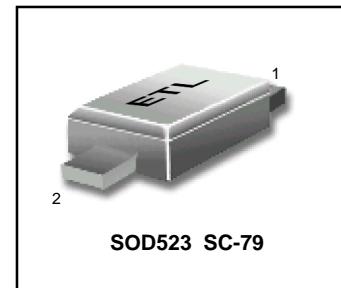
APPLICATIONS

- Electronic tuning in VHF television tuners, band A up to 160 MHz
- Voltage controlled oscillators (VCO).

DESCRIPTION

The BB182B is a planar technology variable capacitance diode, in a SOD523 (SC-79) package. The excellent matching performance is achieved by gliding matching and a direct matching assembly procedure.

BB 182B



LIMITING VALUES In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V_R	continuous reverse voltage		–	34	V
V_{RM}	peak reverse voltage	in series with a 10 kΩ resistor	–	35	V
I_F	continuous forward current		–	20	mA
T_{stg}	storage temperature		–55	+150	°C
T_j	operating junction temperature		–55	+125	°C

ELECTRICAL CHARACTERISTICS $T_j=25^\circ\text{C}$ unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	TYP.	UNIT
I_R	reverse current	$V_R = 32 \text{ V}$; see Fig.2	–	–	10	nA
		$V_R = 32 \text{ V}$; $T_j = 85^\circ\text{C}$; see Fig.2	–	–	200	nA
r_s	diode series resistance	$f = 470 \text{ MHz}$; $V_R = 5\text{V}$	–	–	1.1	Ω
C_d	diode capacitance	$V_R = 2 \text{ V}$; $f = 1 \text{ MHz}$; see Figs 1and 3	47	–	53	pF
		$V_R = 25 \text{ V}$; $f = 1 \text{ MHz}$; see Figs 1and 3	2.65	–	3	pF
$\frac{C_{d(2V)}}{C_{d(25V)}}$	capacitance ratio	$f = 1 \text{ MHz}$	17	–	–	
$\frac{\Delta C_d}{C_d}$	capacitance matching	$V_R = 2 \text{ to } 25 \text{ V}$; in a sequence of 15 diodes(gliding)	–	–	2	%

SEMICONDUCTOR

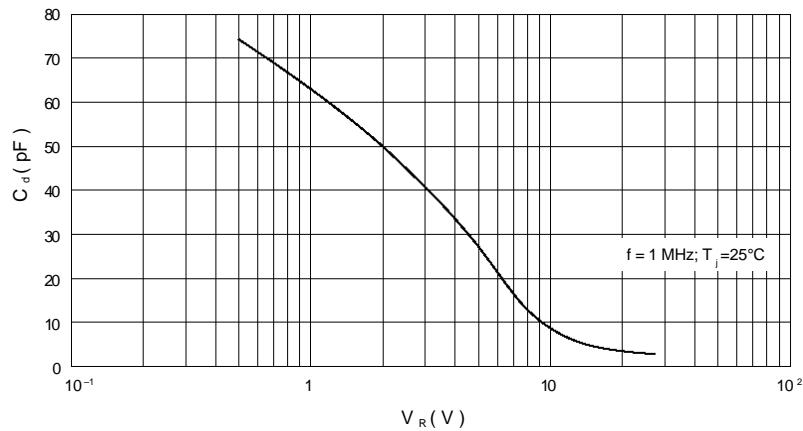
BB 182B


Fig.1 Diode capacitance as a function of reverse voltage; typical values.

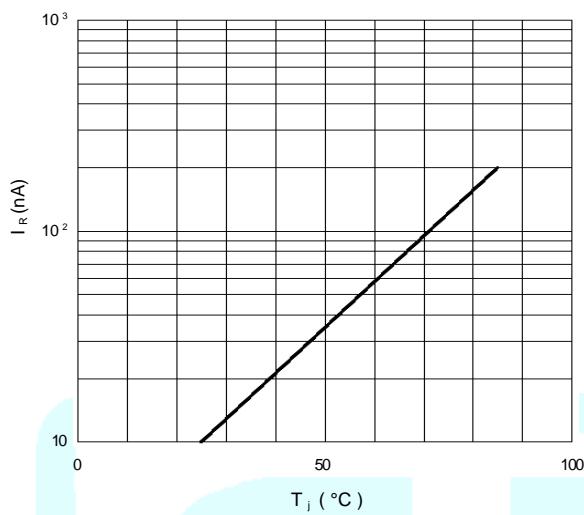


Fig.2 Reverse current as a function of junction temperature; maximum values.

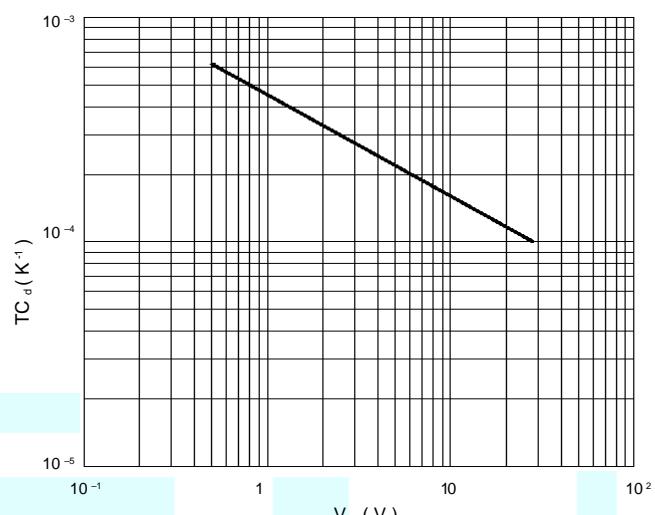


Fig.3 Temperature coefficient of diode capacitance as a function of reverse voltage; typical values.

SEMICONDUCTOR